MA2ZD140G

Silicon epitaxial planar type

For high speed switching

■ Features

• Low forward voltage: V_F < 0.40 V

■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol	Rating	Unit
Reverse voltage	V_R	20	V
Repetitive peak reverse voltage	V _{RRM}	20	V
Forward current (Average)	$I_{F(AV)}$	100	mA
Peak forward current	I_{FM}	300	mA
Non-repetitive peak forward surge current *	I _{FSM}	1	A
Junction temperature	T _j	125	°C
Storage temperature	T_{stg}	-55 to +125	°C

Note) *: The peak-to-peak value in one cycle of 50 Hz sine wave (non-repetitive)

Package

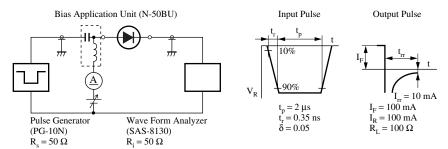
- Code SMini2-F3
- Pin Name
 - 1: Anode
 - 2: Cathode

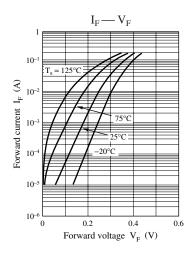
■ Marking Symbol: 2N

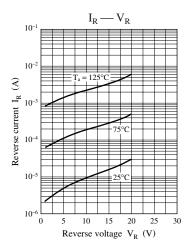
■ Electrical Characteristics $T_a = 25$ °C ± 3 °C

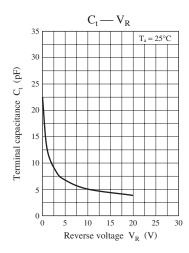
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Forward voltage	V_{F1}	$I_F = 5 \text{ mA}$			0.27	V
	V _{F2}	$I_F = 100 \text{ mA}$			0.40	
Reverse current	I_R	$V_R = 10 \text{ V}$			20	μΑ
Terminal capacitance	C _t	$V_R = 0 V, f = 1 MHz$		25		pF
Reverse recovery time *	t _{rr}	$I_F = I_R = 100 \text{ mA}$		3		ns
		$I_{rr} = 10 \text{ mA}, R_L = 100 \Omega$				

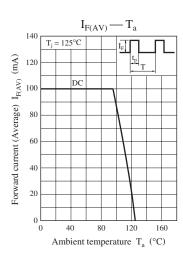
- Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring methods for diodes.
 - 2. This product is sensitive to electric shock (static electricity, etc.). Due attention must be paid on the charge of a human body and the leakage of current from the operating equipment.
 - 3. Absolute frequency of input and output is 250 MHz.
 - 4. *: t_{rr} measurement circuit





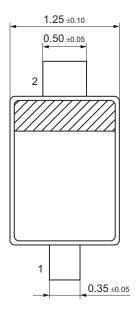


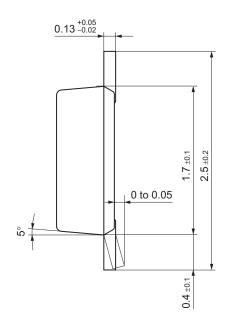


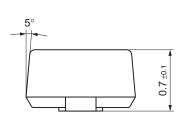


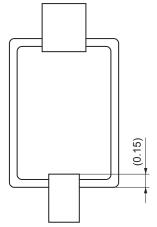
2 SKH00190AED

SMini2-F3 Unit: mm









SKH00190AED 3

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- (6) Comply with the instructions for use in order to prevent breakdown and characteristics change due to external factors (ESD, EOS, thermal stress and mechanical stress) at the time of handling, mounting or at customer's process. When using products for which damp-proof packing is required, satisfy the conditions, such as shelf life and the elapsed time since first opening the packages.
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